Amendment to the Claims:

This listing of claims will replace all prior versions and listings of claims in the application:

Listing of Claims:

- 1. (original) A pre-packaged component device comprising:
 - a first non-conductive substrate member having an outer surface;
- a second non-conductive substrate member having an outer surface;
- a first layer of solderable electrically conductive material secured to the outer surface of said first non-conductive substrate member;
- a second layer of solderable electrically conductive material secured to the outer surface of said second non-conductive substrate member:

and

lead members and a transistor member positioned between said first and second non-conductive substrate members, said transistor having at least one gate.

- 2. (original) The component device as recited in claim 1 wherein said first and second non-conductive substrate members are made from a ceramic material.
- 3. (original) The component device as recited in claim 2 wherein said ceramic material is taken from the group consisting of alumina, aluminum nitride, silicon nitride, and beryllium oxide.
- 4. (withdrawn) The component device as recited in claim 1 wherein said solderable electrically conductive material is a copper material and is direct bonded to said first and second substrate members.

Appl. No. 10/050,344 Amdt. dated April 23, 2004 Reply to Office Action of January 26, 2004

- 5. (original) The component device as recited in claim 1 wherein said lead members comprise a gate pin, a drain member and a source member.
- 6. (original) The component device as recited in claim 5 wherein said lead members are stamped from a copper material during manufacture.
- 7. (withdrawn) The component device as recited in claim 1 further comprising a drain pad positioned on the inside surface of said first nonconductive substrate member and a source pad and gate runner positioned on the inside surface of said second non-conductive substrate member.
- 8. (currently amended) The component device as recited in claim 1 wherein said transistor member is a metal oxide semiconductor field effect transistor (MOSFET) MOSFET.
- 9. (withdrawn, currently amended) The component device as recited in claim 1 wherein said transistor member is an <u>isolated gate bipolar transistor (IGBT)</u> IGBT.
 - 10. (cancelled)
 - 11. (cancelled)
 - 12. (cancelled)
 - 13. (cancelled)
- 14. (New) The component device as recited in claim 1 wherein said lead members comprise a gate pin, a plurality of drain members and a plurality of source members.